



DXTP03200BP5

200V PNP HIGH VOLTAGE TRANSISTOR PowerDI5

Features

- $BV_{CEO} = -200V$
- I_C = -2A High Continuous Collector Current
- ICM = -5A Peak Collector Current
- P_D up to 3.2W
- 43% smaller than SOT223; 60% smaller than TO252 (DPAK)
- Maximum height just 1.1mm
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Application

- DC DC Conversion
- Telecoms
- **Power Management**

Mechanical Data

- Case: PowerDI®5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.093 grams (Approximate)

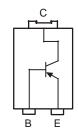


Top View



Bottom View

F **Device Schematic**



Pin-Out Diagram

Ordering Information (Note 4)

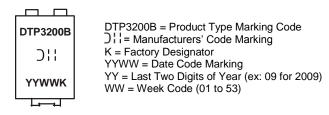
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXTP03200BP5-13	AEC-Q101	DTP3200B	13	16	5,000
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.					

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



PowerDI is a registered trademark of Diodes Incorporated



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-220	V
Collector-Emitter Voltage	V _{CEO}	-200	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-2	A
Base Current	IB	-1	A
Peak Pulse Current	I _{CM}	-5	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ heta JA}$	39	°C/W
Power Dissipation (Note 6)	PD	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{ heta JA}$	75	°C/W
Power Dissipation (Note 7)	PD	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 7)	$R_{ heta}$ JA	169	°C/W
Thermal Resistance, Junction to Lead (Note 8)	R _{θJL}	5.6	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 9)

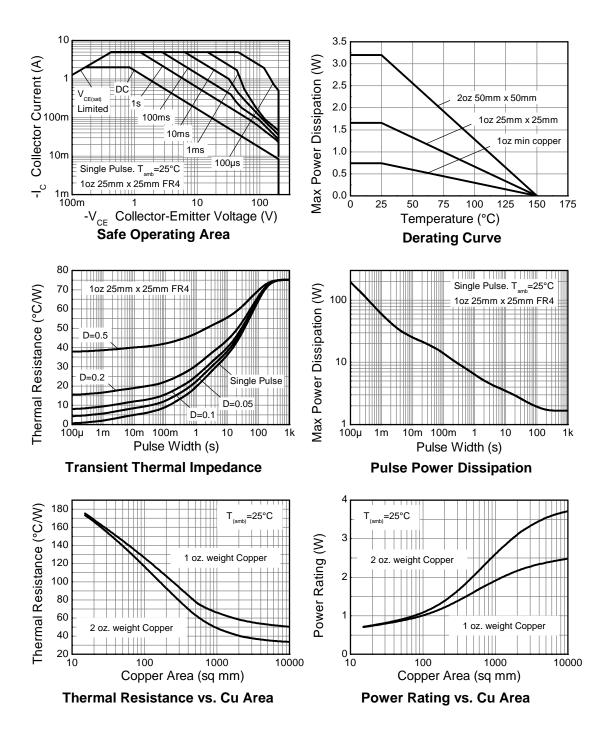
Notes:

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.
Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.
Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.
Thermal resistance from junction to solder-point (on the exposed collector pad).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

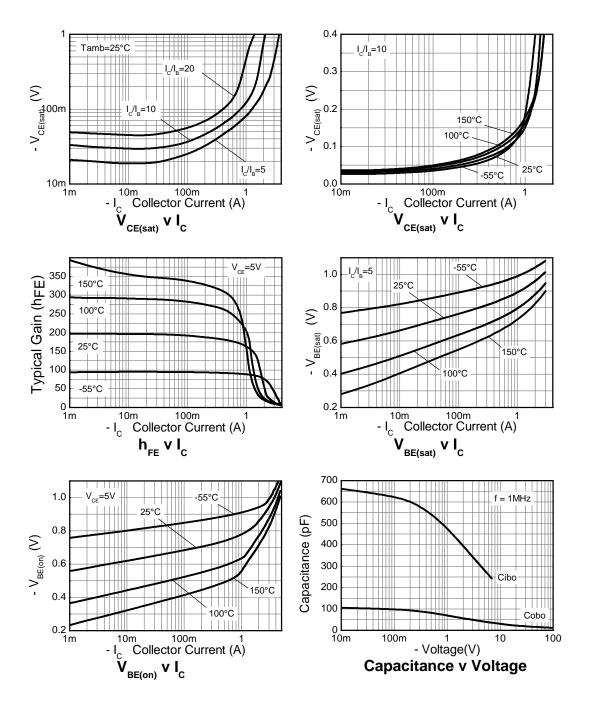
Characteristic	Cumple of	Min	True	Max	11	Test Condition
Characteristic	Symbol	Min	Тур	Max	Unit	
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-220	-245	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	V _{(BR)CEO}	-200	-225	-	V	$I_{C} = -10 \text{mA}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7	-8.4	-	V	I _E = -100μA
Collector Cutoff Current	Ісво	_	<1	-50	nA	V _{CB} = -200V
	.080		-	-0.5	μA	V _{CB} = -200V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	-	<1	-10	nA	$V_{EB} = -6V$
		-	-37	-50	mV	$I_{C} = -0.1A, I_{B} = -10mA$
Collector-Emitter Saturation Voltage (Note 10)	Varia	-	-130	-155		I _C = -0.5A, I _B = -25mA
Collector-Emiller Saturation Voltage (Note TO)	V _{CE(sat)}	-	-135	-160	IIIV	I _C = -1A, I _B = -100mA
		-	-180	-275		I _C = -2A, I _B = -400mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-955	-1,100	mV	$I_{C} = -2A, I_{B} = -400mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	-	-860	-1,000	mV	$V_{CE} = -5V, I_C = -2A$
		100	195	-		$V_{CE} = -5V, I_{C} = -10mA$
DC Current Coin (Note 10)	L	100	170	300		$V_{CE} = -5V, I_{C} = -1A$
DC Current Gain (Note 10)	h _{FE}	20	50	-	_	$V_{CE} = -5V, I_{C} = -2A$
		-	5	-		$V_{CE} = -5V, I_{C} = -5A$
Transition Frequency	f _T	-	105	-	MHz	V _{CE} = -10V, I _C = -100mA, f = 50MHz
Output Capacitance	Cobo	-	31	-	pF	V _{CB} = -10V, f = 1MHz
Delay Time	t _d	_	21	-	ns	
Rise Time Storage Time		-	18	-	ns	$V_{CC} = -50V, I_C = -1A,$
		-	680	-	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$
Fall Time	t _f	_	75	-	ns	

Note: 10. Pulse Test: Pulse width \leq 300µs. Duty cycle \leq 2.0%.



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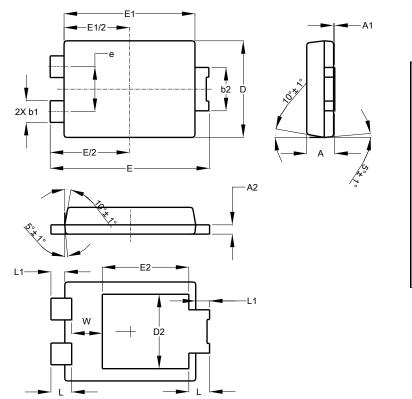
Typical Characteristics





Package Outline Dimensions

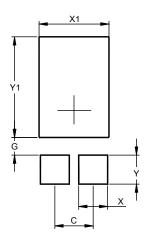
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



		(0)			
POWERDI [®] 5					
Dim	Min	Max	Тур		
Α	1.05	1.15	1.10		
A1	0.00	0.05			
A2	0.33	0.43	0.381		
b1	0.80	0.99	0.89		
b2	1.70	1.88	1.78		
D	3.90	4.05	3.966		
D2		-	3.054		
Е	6.40	6.60	6.504		
е			1.84		
E1	5.30	5.45	5.37		
E2			3.549		
L	0.75	0.95	0.85		
L1	0.50	0.65	0.57		
W	1.10	1.41	1.255		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	1.390
X1	3.360
Ý	1.400
Y1	4.860

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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